Silicon Tracking System of BM@N experiment (BM@N STS)

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Silicon Tracking System (STS)



Technical solutions:

- double-sided silicon microstrip sensors
 - hit spatial resolution $~\approx 25~\mu m$
 - material budget per tracking station: $\approx 0.3\% 2\% X_0$
 - radiation tolerance up to 1×10^{14} n/cm² (1 MeV equivalent)
- self-triggering front-end electronics, time-stamp resolution $\approx 12,5$ ns
- Iow-mass detector modules/ladders

The project is being implemented as a joint effort of CBM and BM@N STS teams under the GSI-JINR Roadmap Agreement

STS team

Performance simulations







DCM-QGSM model, Au+Au, T₀=4 AGeV

Eff. >90% for 1 < P < 2.5 GeV/c, 80% for P > 4 GeV/c;

Δp/p ~ 0.6%



Equivalent neutron fluence n_{eq}/cm^2



Ionizing dose in Gray

- Ionizing dose ~ 100 Gy/lifetime;
- The equivalent neutron life time fluence of 10¹¹ n_{eq}/cm²

STS Modules



Time diff for hits Sts 3 N and Sts 3 P

Ladder assembly



Each sensor has fiducial marks on its surface. Position of each mark is specified for each module on a specific ladder.

Deviation of the measured position of the fiducial from the specified one are shown on the right plot.







Measured noise per channel distribution 1 the module on ladder Signal/Noise > 25

Readout electronics



Thank you for your attention!

Backup slides >>>>